END SEMESTER EXAMINATION, NOVEMBER-2018

Semester: 3rd

Subject Code: CAI-301

PRINCIPLES OF ELECTRICAL AND ELECTRONICS ENGINEERING

Full Marks - 70

Time - Three hours

The figures in the margin indicate full marks for the questions

PART - A

Marks - 25

Answer all the questions.

I. Fill in the blanks:

1×10=10

- (a) If $e_1 = A \sin \omega t$ and $e_2 = B \sin (\omega t - \phi)$, then e, by 0
- 3 degrees. In a series R-L circuit, V_L leads V_R by
- 0 connected in series, then the total resistances If the resistances R, = 6Ω and R₂ = 3Ω are

57/CAI-301/PoE&EE (2)	(c) When an input signal 1 is applied to a NOT gate, the output is 0.	(b) The number of depletion layer in a transistor is one.	(a) Semiconductor materials have covalent bonds.	2. Write true or false: 1×10=10	(j) The NAND gate is AND gate followed by gate.	(i) A Zener diode is adevice.	(h) A transformer works ononly.	bias.	(g) Junction breakdown occurs under	(f) For a silicon diode, the value of the forward bias voltage typically must be greater than V.	junction is calledvoitage.	(e) Any voltage that is connected across a p-n	(d) The process of adding impurities to pure
57/CAI-301/PoE&EE (3) [Turn over	+ (A)		unbalanced power is	(a) The minimum number of wattmeter(s) required to measure 3-phase, 3 wire balanced or	3. Choose the correct answer: 1×5=5	(j) Transformers are rated in kW.	(i) The base of a transistor is lightly doped.	(h) A Zener diode is always forward connected.	(g) A p-n junction acts as a unidirectional switch.	(f) A semiconductor has generally 4 valence electrons.	(e) An n-type semiconductor is positively charged.	the algebraic sum of the currents meeting at a point (or junction) is zero.	

- (b) Electronic distribution of an Si atom is
- (i) 2, 10, 2
- (ii) 2, 8, 4
- (iii) 2, 7, 5
- (iv) 2, 4, 8
- <u></u> Without a DC source, a clipper acts like a
- (i) rectifier
- (ii) clamper
- (iii) demodulator (iv) chopper
- (d) The following relationship between α and β are correct except
- 3 $\beta = \frac{\alpha}{1-\alpha}$
- (ii) $\alpha = \frac{\beta}{1-\beta}$
- (iii) $\alpha = \frac{\beta}{\beta}$ 1+8
- (iv) 1-a=-
- (e) The emitter of a transistor is generally doped the heaviest because it
- has to dissipate maximum power
- (ii) has to supply the charge carriers
- (iii) is the first region of the transistor
- (iv) must possess low resistance
- 57/CAI-301/PoE&EE (4)

Marks - 45 PART - B

Answer Q. No. 8 and any three from the rest.

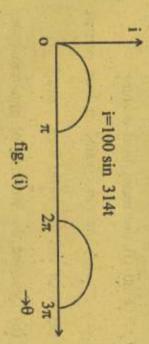
- 4. (a) Define: Form factor, Phase difference.
- (b) Derive the following relation:

$$I = \frac{1}{\sqrt{2}}$$

where, I is r.m.s value of current

In is maximum value of current.

(c) Calculate the form factor and peak factor of the sine wave shown in fig. (i).



- 5. (a) What is the function of transformer?
- (b) If the resistances $R_1 = 2\Omega$, $R_2 = 4\Omega$, $R_3 = 6\Omega$ are connected in parallel, then what will be the equivalent resistance?

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- (c) A transformer takes a current of 0.6A and absorbs 64W when primary is connected to its normal supply of 200V, 50 Hz; the secondary being open-circuit. Find the magnetising and iron loss currents.
- 6. (a) What are p-type and n-type semiconductors?

(b) Describe forward and reverse biasing of a p-n junction.

(c) A full-wave rectifier uses two diodes, the internal resistance of each diode may be assumed constant at 20Ω. The transformer r.m.s secondary is 50V and load resistance is 980Ω.

Find (i) the mean load current

(ii) the r.m.s value of load current. 5

- 7. (a) What are the basic logic gates?
- (b) Describe the working of npn transistor. 3
- (c) In a common base connection, current amplification factor is 0.9. If the emitter current is 1 mA, determine the value of base current.

- 8. Write short notes on any three:
- 5×3=1
- (a) R-L-C series circuit
- (b) Relation between line current and phase currents in delta connected 3-phase system
- (c) Zener diode as voltage stabiliser
- (d) Centre-tap full-wave rectifier
- (e) Power measurement by two wattmeter method.

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